imall

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



Contact us

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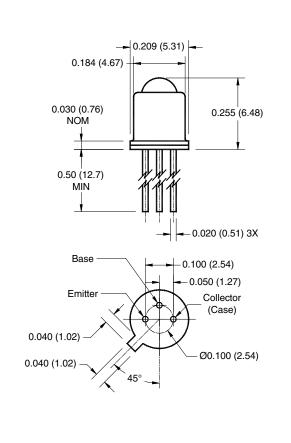




BPW38 HERMETIC SILICON PHOTODARLINGTON

SEMICONDUCTOR®

PACKAGE DIMENSIONS



NOTES:

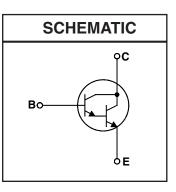
- 1. Dimensions for all drawings are in inches (mm).
- 2. Tolerance of \pm .010 (.25) on all non-nominal dimensions unless otherwise specified.

FEATURES

- Hermetically sealed package
- Narrow reception angle
- European "Pro Electron" registered

DESCRIPTION

• The BPW38 is a silicon photodarlington mounted in narrow angle TO-18 package.



- 1. Derate power dissipation linearly 3.00 mW/°C above 25°C ambient.
- 2. Derate power dissipation linearly 6.00 mW/°C above 25°C case.
- 3. RMA flux is recommended.
- 4. Methanol or isopropyl alcohols are recommended as cleaning agents.
- 5. Soldering iron tip 1/16" (1.6mm) minimum from housing.
- 6. As long as leads are not under any stress or spring tension.
- 7. Light source is a GaAs LED emitting light at a peak wavelength of 940 nm.

ABSOLUTE MAXIMUM RATINGS (T _A = 25°C unless otherwise specified)								
Parameter	Symbol	Symbol Rating						
Operating Temperature	T _{OPR}	-65 to +125	°C					
Storage Temperature	T _{STG}	-65 to +150	°C					
Soldering Temperature (Iron) ^(3,4,5 and 6)	T _{SOL-1}	240 for 5 sec	°C					
Soldering Temperature (Flow) ^(3,4 and 6)	T _{SOL-F}	260 for 10 sec	°C					
Collector-Emitter Voltage	V _{CEO}	25	V					
Collector-Base Voltage	V _{CBO}	25	V					
Emitter-Base Voltage	V _{EBO}	12	V					
Power Dissipation $(T_A = 25^{\circ}C)^{(1)}$	PD	300	mW					
Power Dissipation $(T_C = 25^{\circ}C)^{(2)}$	PD	600	mW					

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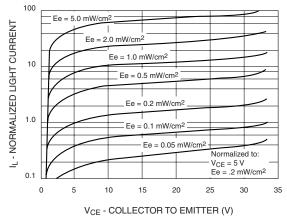
ELECTRICAL / OPTICAL CHARACTERISTICS (TA = 25°C
ELECTRICAL / OFFICAL CHARACTERISTICS (TA =23 C

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ELECTRICAL / OPTICAL CHARACTERISTICS (T _A =25°C) (All measurements made under pulse conditions)									
PARAMETER	TEST CONDITIONS	SYMBOL	MIN	ТҮР	MAX	UNITS			
Collector-Emitter Breakdown	$I_{\rm C} = 10 \text{ mA}, \text{ Ee} = 0$	BVCEO	25	—		V			
Emitter-Base Breakdown	$I_{E} = 100 \ \mu A, Ee = 0$	BVebo	12	_		V			
Collector-Base Breakdown	$I_{\rm C} = 100 \ \mu \text{A}, \ \text{Ee} = 0$	ВУсво	25	_		V			
Collector-Emitter Leakage	$V_{CE} = 12 V, Ee = 0$	ICEO	—	_	100	nA			
Reception Angle at 1/2 Sensitivity		θ	_	±8		Deg.			
On-State Collector Current	Ee = 0.125 mW/cm ² $V_{CE} = 5 V^{(7)}$	IC(ON)	7.5	_	—	mA			
Rise Time	$I_{\rm C}$ = 10 mA, $V_{\rm CC}$ = 10 V R _L = 100 Ω	t _r	_	300	—	μs			
Fall Time	$I_{\rm C}$ = 10 mA, V _{CC} = 10 V R _L = 100 Ω	t _f	_	250	_	μs			

TYPICAL PERFORMANCE CURVES





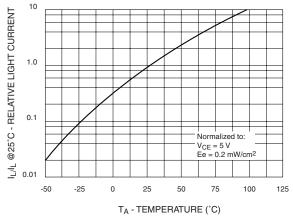


Fig. 2 Relative Light Current vs. Ambient Temperature



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TYPICAL PERFORMANCE CURVES

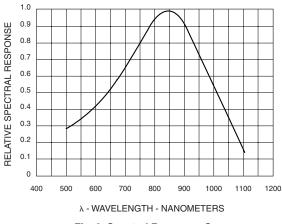


Fig. 3 Spectral Response Curve

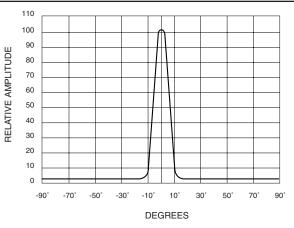


Fig. 4 Angular Response

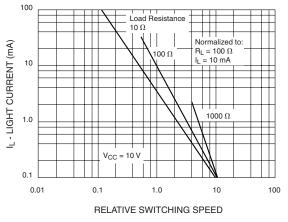
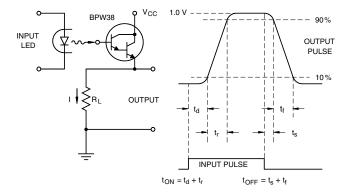


Fig. 5 Light Current vs. Relative Switching Speed







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- 2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.